






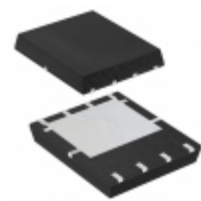


	<b>DMT6010SCT</b>	
	<b>Hersteller-Teilenummer:</b>	DMT6010SCT
	<b>Hersteller / Marke:</b>	Diodes Incorporated
	<b>Teil der Beschreibung:</b>	MOSFET N-CHA 60V 98A TO220
	<b>Datenblätter:</b>	 <a href="#">DMT6010SCT.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 90000 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

### Spezifikationen

Teilenummer	DMT6010SCT
Hersteller	Diodes Incorporated
Beschreibung	MOSFET N-CHA 60V 98A TO220
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	90000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	2.3W (Ta), 104W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	98A (Tc)
Rds On (Max) @ Id, Vgs	7.2 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	36.3nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1940pF @ 30V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tube



















































DMT6010SCT ist neu im Original, Suche DMT6010SCT Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMT6010SCT Diodes Incorporated mit Garantie und Vertrauen.  
Anfrage DMT6010SCT: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>DMT6010LFG-13</b> Diodes Incorporated MOSFET N-CH 60V 13A POWERDI</p>	 <p><b>DMT6010LFG-7</b> Diodes Incorporated MOSFET N-CH 60V 13A POWERDI</p>	 <p><b>DMT6010LSS</b> Diodes Incorporated DMT6010LSS DIODES</p>	 <p><b>DMT6010LSS-13</b> Diodes Incorporated MOSFET BVDSS: 41V 60V SO-8 T&amp;R 2</p>
 <p><b>DMT6015LFV-7</b> Diodes Incorporated MOSFET NCH 60V 9.5A POWERDI</p>	 <p><b>DMT6010LPS-13</b> Diodes Incorporated MOSFET N-CH 60V 13.5A</p>	 <p><b>DMT6015LFV</b> Diodes Incorporated DMT6015LFV DIODES</p>	 <p><b>DMT6012LPS-13</b> Diodes Incorporated MOSFET N-CH 60V POWERDI</p>

### heiße Teile

Mehr

 DMT3020LSD	 DMT32M5LPS	 DMT4011LFG-7	 DMT40M9LPS-13	 DMT6004LPS-13
 DMT6004SPS	 DMT6004SPS-13	 DMT6005LPS	 DMT6005LPS-13	 DMT6005LSS
 DMT6008LFG	 DMT6008LFG-7	 DMT6009LCT	 DMT6009LFG	 DMT6009LFG-13
 DMT6009LK3	 DMT6009LPS	 DMT6009LPS-13	 DMT6009LSS	 DMT6010LFG
 DMT6010LFG-13	 DMT6010LFG-7	 DMT6010LPS-13	 DMT6010LSS	 DMT6010LSS-13
 DMT6015LFV	 DMT6015LFV-13	 DMT6015LFV-7	 DMT6015LPS-13	 DMT6015LSS
 DMT6015LSS-13	 DMT6016LSS	 DMT6016LSS-13	 DMT6017LSS	 DMT6017LSS-13
 DMT69M8LSS	 DMT8012LSS	 DMTH3004LK3	 DMTH3004LK3Q	 DMTH4004LK3
 DMTH4004LK3-13	 DMTH4004LPS	 DMTH4004LPS-13	 DMTH4004SCTB	 DMTH4004SPS
 DMTH4005SK3	 DMTH4005SK3Q	 DMTH4005SPS	 DMTH4007LK3	 DMTH4007LK3-13

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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